

# **Excellent Integrated System Limited**

Stocking Distributor

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Vishay/Siliconix SI4864DY-T1-E3

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>





### Si4864DY

RoHS

COMPLIANT

HALOGEN FREE Available

Vishay Siliconix

## N-Channel 20-V (D-S) MOSFET

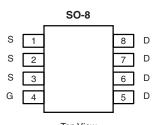
PRODUCT SUMMARY					
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω <b>)</b>	I <sub>D</sub> (A)			
20	0.0035 at $V_{GS}$ = 4.5 V	25			
	0.0047 at V <sub>GS</sub> = 2.5 V	20			

#### FEATURES

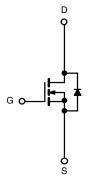
- Halogen-free According to IEC 61249-2-21
  Available
- TrenchFET<sup>®</sup> Power MOSFETs: 2.5 V Rated
- Low 3.5 mΩ R<sub>DS(on)</sub>
- PWM (Q<sub>gd</sub> and R<sub>g</sub>) Optimized

#### **APPLICATIONS**

 Low-Side MOSFET in Synchronous Buck DC/DC Converters in Servers and Routers



Top View



Ordering Information: Si4864DY-T1-E3 (Lead (Pb)-free) Si4864DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b> $T_A = 25 \degree C$ , unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	20		V	
Gate-Source Voltage		V <sub>GS</sub>	± 8			
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	25	17		
	T <sub>A</sub> = 70 °C		20	13		
Pulsed Drain Current (10 µs Pulse Width)		I <sub>DM</sub>	60		A	
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	2.9	1.3		
	T <sub>A</sub> = 25 °C	PD	3.5 1.6		W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	'D	2.2	1	1	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum hursting to Archiegta	t ≤ 10 s	R <sub>thJA</sub>	29	35	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		67	80	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	13	16	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.



## Si4864DY

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<b>SPECIFICATIONS</b> $T_J = 25 \text{ °C}$ , unless otherwise noted							
Parameter	Symbol	Test Conditions		Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	0.6		2	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 100	nA	
Zero Gate Voltage Drain Current		$\begin{tabular}{ c c c c c } \hline V_{DS} &= 20 \text{ V}, \text{ V}_{GS} &= 0 \text{ V} \\ \hline V_{DS} &= 20 \text{ V}, \text{ V}_{GS} &= 0 \text{ V}, \text{ T}_{\text{J}} &= 55 \ ^{\circ}\text{C} \\ \hline \end{tabular}$			1	μA	
	IDSS				5		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5$ V, $V_{GS} = 4.5$ V	30			А	
Drain-Source On-State Resistance <sup>a</sup>	Б	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 25 \text{ A}$		0.0028	0.0035	Ω	
	R <sub>DS(on)</sub>	V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 20 A		0.0038	0.0047		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 6 V, I_{D} = 25 A$		70		S	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{\rm S}$ = 2.9 A, $V_{\rm GS}$ = 0 V		0.70	1.1	V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg			47	70		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = 10 V, $V_{GS}$ = 4.5 V, $I_{D}$ = 25 A		10		nC	
Gate-Drain Charge	Q <sub>gd</sub>			13.4			
Gate Resistance	Rg		0.5	1.5	2.6	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			40	60		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 10 $\Omega$		44	65		
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D}\cong\text{1}$ A, $\text{V}_\text{GEN}$ = 4.5 V, $\text{R}_\text{g}$ = 6 $\Omega$		150	240	ns	
Fall Time	t <sub>f</sub>			72	110		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = 2.9 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		57	80		

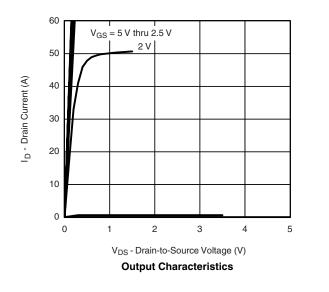
Notes:

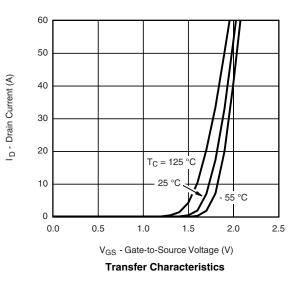
a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







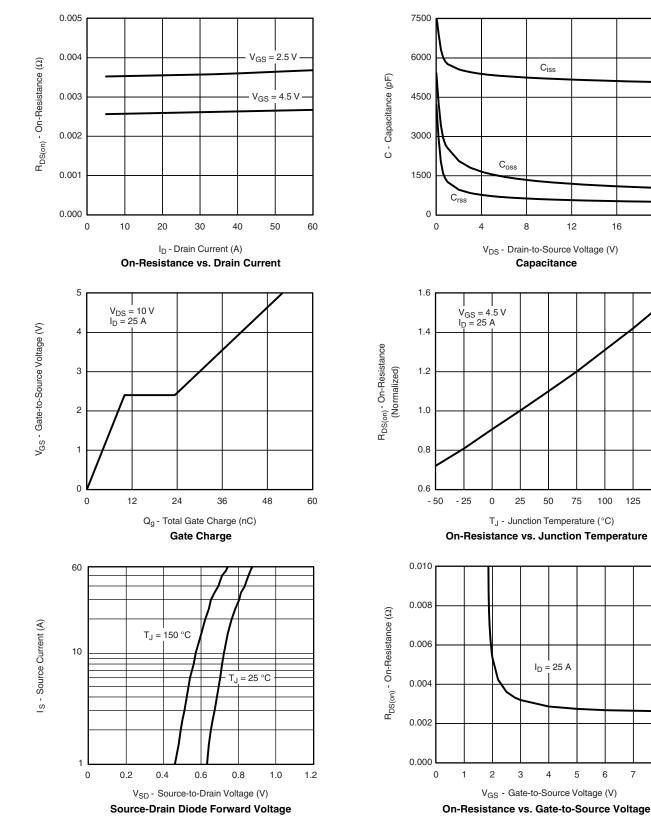


## Si4864DY

20

16

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#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

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8

6

125

150

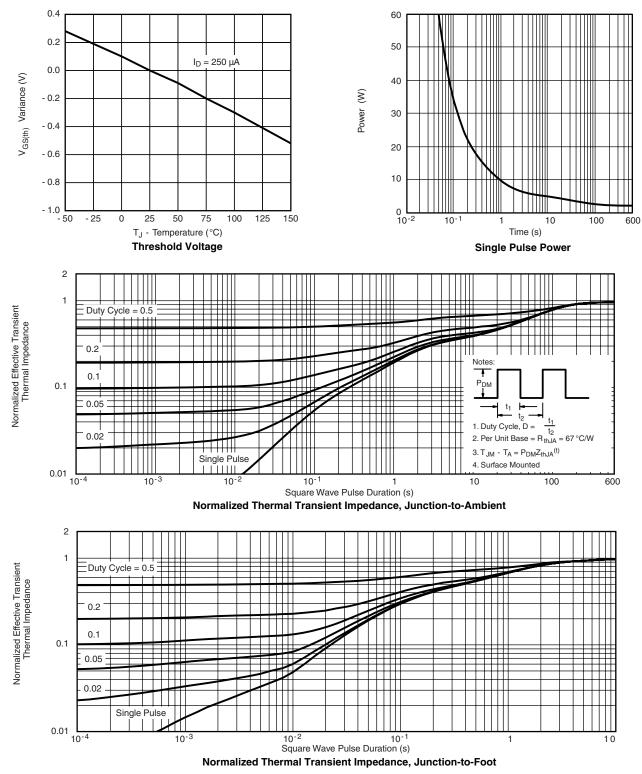


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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg?71449</u>.

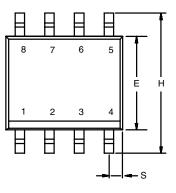


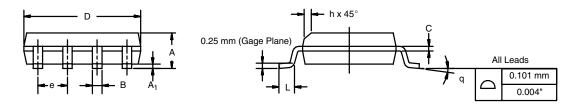


## **Package Information**

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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIM	IETERS	INCHES		
DIM	Min	Max	Min	Мах	
A	1.35	1.75	0.053	0.069	
A <sub>1</sub>	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498					

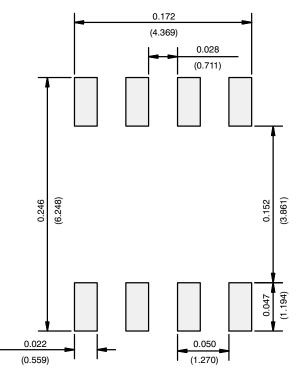


### **Application Note 826**

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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